

View Online at <https://aerobasegroup.com/nsn/5961-01-135-4118>

Inclosure Material:

Ceramic

Overall Length:

Between 0.750 inches and 0.785 inches

Overall Height:

0.200 inches

Overall Width:

Between 0.245 inches and 0.271 inches

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-116-2

Component Name And Quantity:

16 semiconductor device diode

Mounting Method:

Terminal

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

1.5 forward voltage, dc all semiconductor device diode and 60.0 repetitive peak reverse voltage all semiconductor device diode

Current Rating Per Characteristic:

350.00 milliamperes source cutoff current preset all transistor

Power Rating Per Characteristic:

650.0 milliwatts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

14 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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